## EE 435

Homework 2
Spring 2024
Due Friday Feb 2
Problem 1 and 2 Consider the following operational amplifier. The goal is to obtain an expression for the small-signal output voltage in terms of the input variables $\mathrm{V}_{\text {IN }}^{+}$and $\mathrm{V}_{\text {IN }}^{-}$.
a) Write a complete set of small-signal equations that can be solved to obtain Vout. Assume the small-signal parameter $\mathrm{g}_{\mathrm{o}}$ is present in all MOS devices.
b) Solve these equations by hand for Vout but, if you do not have a solution at the end of $1 / 2$ hour, stop, and comment on your progress and the amount of effort that you believe would be required to finish the solution.
c) Obtain a parametric (symbolic) solution for the transfer function $V_{\text {OUT }} / V_{\text {IN }}$ from this set of equations with MATLAB. This solution will be the ratio of two polynomials in s . Each coefficient will be comprised of the sum of a number of product terms. How many total product terms appear in this solution? In this part, $\mathrm{Vin}=\mathrm{V}_{\text {in }}{ }^{+}-\mathrm{V}_{\text {in }}{ }^{-}$
d) Simplify the solution obtained with MATLAB under the assumption that all $g_{o}$ terms are small compared to $g_{m}$ terms


Problem 3 A transresistance amplifier with a gain $\mathrm{R}_{\mathrm{T}}$ is shown. Derive an expression for the voltage gain of the amplifier as a function of the transresistance gain $\mathrm{R}_{\mathrm{T}}$ and determine what that reduces to if $\mathrm{R}_{\mathrm{T}}$ is very large.

Problem 4 Assume the amplifier shown below is designed in a $0.18 \mu$ CMOS process. Assume also that $\mathrm{V}_{\mathrm{DD}}=1 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-1 \mathrm{~V}$, and $\mathrm{I}_{\mathrm{DQ}}=4 \mathrm{~mA}$.
a) Analytically determine the W and L needed to establish a quiescent output voltage of 0.5 V when $\mathrm{V}_{\mathrm{IN}}=0.5 \mathrm{~V}$.

b) Verify the transfer characteristics by Spice simulation.
c) Analytically determine the dc voltage gain at the Q-point established in a)
d) Using SPICE, obtain a plot of the small signal voltage gain versus the quiescent output voltage.

Problem 5 and $6 \quad$ Design a 5 T op amp to have a dc gain of 50 dB and a GB of 2 MHz in the $\mathrm{ON} 0.5 \mu \mathrm{~m}$ CMOS process. Assume $\mathrm{V}_{\mathrm{DD}}=3.5 \mathrm{~V}$ and $\mathrm{C}_{\mathrm{L}}=1 \mathrm{pF}$. Assume also that the bias voltages $\mathrm{V}_{\mathrm{B} 1}$ and $\mathrm{V}_{\mathrm{B} 2}$ can be precisely set so that a CMFB circuit is not needed. Verify the gain and the GB of your design with a SPICE simulation.


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Problem 7 Determine the common-mode input range and the output signal swing of the amplifier you designed in the previous problem.

Problem 8 Assume that the op amp is a single-pole amplifier with gain given by the expression $A(s)=\frac{A_{0} \omega_{A}}{s+\omega_{A}} \cong \frac{G B}{s}$ where the gain-bandwidth product of the op amp is $\mathrm{GB}=\mathrm{A}_{0} \omega_{\mathrm{A}}$. The right-most approximation to the gain is almost always justifiable when used to characterize the operational amplifier since the gain of the op amp is so large at dc and since at frequencies even modestly above $\omega_{\mathrm{A}}$, there is little difference between the middle term and the right term in this expression.
a) Assuming that the frequency-dependent gain of the op amp can be modeled as $A(s) \cong \frac{G B}{s}$, determine the transfer function $A_{F B}(s)=\frac{V_{\text {OUT }}(s)}{V_{I N}(s)}$ for the following two amplifiers
b) With the same op amp model used in part a), analytically determine the 3 dB bandwidth of the following two amplifiers.


Problem 9 It was stated in class that all even-ordered distortion terms introduced by the amplifier vanish in symmetric fully differential amplifiers. Prove this fact.
(Hint: assume that if an ideal differential sinusoidal signal is applied at the input, one of the single-input outputs is given by the expression

$$
V_{\text {out1 } 1}(t)=A_{1} \sin \left(\omega_{1} t+\theta_{1}\right)+\sum_{k=2}^{\infty} A_{k} \sin \left(k \omega_{1} t+\theta_{k}\right)
$$

where $\omega_{1}$ is the frequency of the sinusoidal input and the parameters $A_{2}, A_{3}, \ldots$ and $\theta_{2}, \theta_{3}$, ... characterize the distortion introduced by the amplifier.)

Problem 10 (Extra Credit) The "dead network" of a circuit is obtained by setting all small-signal inputs to 0 . That is, by replacing all ac voltage sources with short circuits and all ac current sources with open circuits. The $\beta$ of a feedback amplifier is a characteristic of the "dead network". Consider the basic inverting and noninverting feedback amplifiers shown below. These are widely used as small-signal voltage amplifiers.

a) Show that they both have the same "dead network"
b) The $\beta$ of the two amplifiers shown is $\beta=\frac{R_{1}}{R_{1}+R_{2}}$. Show that the gain of the noninverting feedback amplifier can be expressed by the standard feedback equation

$$
A_{\mathrm{VF}}=\frac{\mathrm{V}_{\mathrm{OUT}}}{\mathrm{~V}_{\mathrm{IN}}}=\frac{A_{\mathrm{V}}}{1+A_{\mathrm{V}} \beta}
$$

c) Take the limit at $\mathrm{A}_{\mathrm{v}}$ goes to $\infty$ for the gain derived in part b) and compare with that derived in EE 230 for the gain of the noninverting feedback amplifier.
d) Derive the gain of the inverting feedback amplifier in terms of $A_{v}$ and $\beta$ and comment on why it does not look like the standard feedback equation.

